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Estimating Single-Insult Failure Probabilities from Multiple-Insult Accelerated Tests

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Estimating Single-Insult Failure Probabilities from Multiple-Insult Accelerated Tests

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Overview

- Motivation and Motivating Example
- Probability Model
- Application
- Software

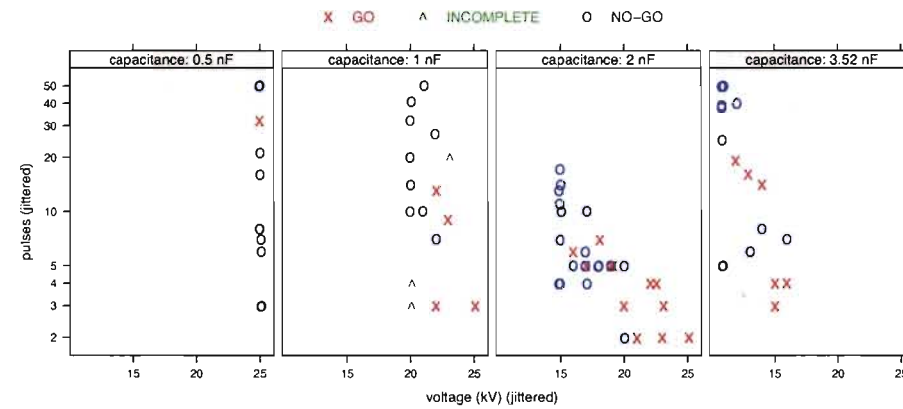
Motivation

- If a worker or an environment “insults” a detonator (det), how will det respond?
- An insult could be a physical shock (drop a tool on a det), electrostatic discharge (worker shuffles their feet while walking), etc.
- The det’s response could be either “Go” or “No-Go”
- Engineers/Researchers want to know $\text{Pr}(\text{Go})$ for a single insult

Example from LANL

- ESD is controlled using voltage (kV) and capacitance (nF)
- Model $\Pr(\text{Go})$ as a function of voltage and energy (mJ) where $E = \frac{1}{2}cv^2$
- It is believed that a det will Go if both energy and voltage exceed some unknown threshold value
- Interested in estimating:
 - $\Pr(\text{Go})$ for a single insult
 - Voltage, Energy combinations that give 1×10^{-6} probability on first insult
- Dets are expensive therefore multiple insults are applied to each det
- Model needs to account for potential degradation with each additional insult

Example from LANL



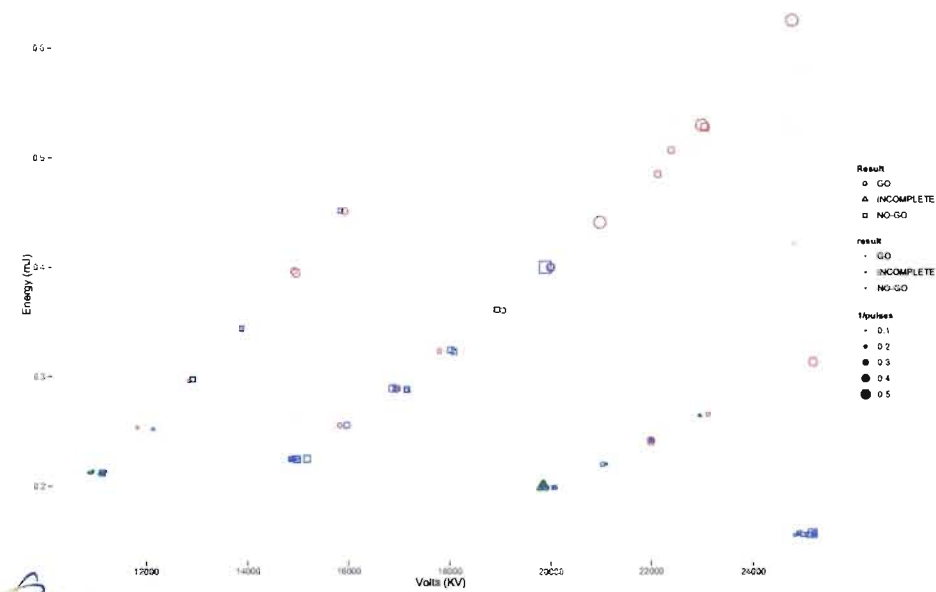
Example from LANL

- 75 dets were exposed to different levels of electric static discharge (ESD)
- Data contains:
 - Identifier for det
 - Capacitance and voltage for which a det was tested
 - Number of insults till either a Go or operator determines that det will never Go (No-Go)
 - Response, either Go or No-Go
 - 3 censored observations
- Censored observations occurred because operator determined det was being tested at too low of energy (E) and voltage (V) combination and moved to higher conditions (to conserve resources)

Model Motivation

- The fraction of units that will go with repeated insults varies with E and V
 - Model assumes limited failure population (LFP)
- Det experts claim that both E and V must exceed thresholds for a Go to occur
 - Model incorporates soft thresholds with E and V

Example from LANL



Probability Model

- Notation:
 - N is the number of insults till an event (Go/No-Go)
 - x_i is accelerating variable i which needs to exceed a soft threshold for $i = 1, \dots, k$
 - p is the proportion of the population that will Go (equivalently the probability of a Go for an infinite number of hits)
 - $F_i(N; \theta_i, x_i)$ is the cumulative probability for a det that will Go when x_i is the limiting factor
 - θ_i is the parameter vector for distribution function F_i

Probability Model

- For an integer n

$$\Pr(N \leq n) = pF(n) = pF_1(n; \theta_1, x_1) \cdots F_k(n; \theta_k, x_k)$$

- Notice that as $n \rightarrow \infty$, $\Pr(N \leq n) \rightarrow p$, the failure proportion
- We model F_i using the Extended Generalized Gamma (EGG) Family of distributions $\forall i$
- $\theta_i = (\mu_i, \sigma_i, \lambda_i)$
- We assume that:
 - $\mu = \mathbf{X}\alpha$
 - $\log(\sigma) = \mathbf{X}\beta$
 - $\lambda = \mathbf{X}\gamma$
 - $\text{logit}(p) = \mathbf{X}\delta$

EGG Family

- For fixed λ , EGG are log-location-scale distributions
- $\lambda = 0$ yields lognormal
- $\lambda = 1$ yields Weibull
- Vander Wiel (2009) reparameterizes this family so that if $Y \sim \text{EGG}(m, s, \lambda)$, $\log(Y)$ has median m and density at m equal to $1/\sqrt{2\pi}s$ regardless of λ (Scott's EGG distribution)

Likelihood Contribution

- If a Go is observed at insult n , we treat as a discrete event $pF(n) - pF(n - 1)$
- If a No-Go is observed, then we use $1 - p$ (survival function with $n = \infty$)
- If unit is censored at insult n , we treat as right censored $1 - pF(n)$

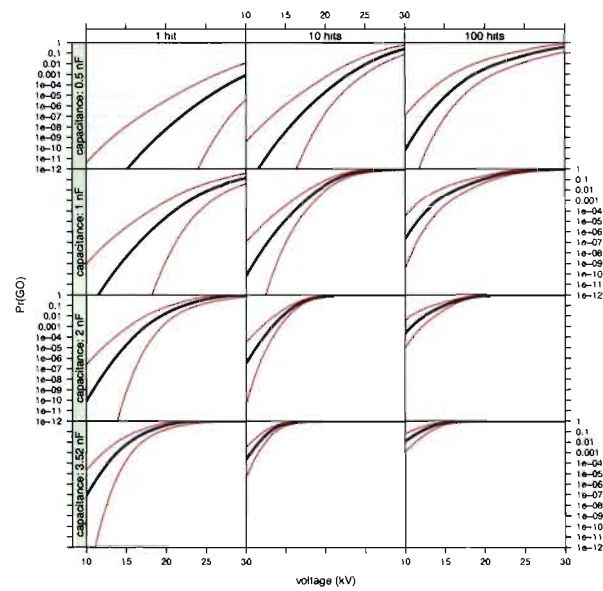
Prior Distributions

- $\alpha \sim$ wide normal
- $\beta \sim$ wide normal
- γ is not assigned a distribution (i.e., we assume we know this value)
- $\delta \sim$ wide normal

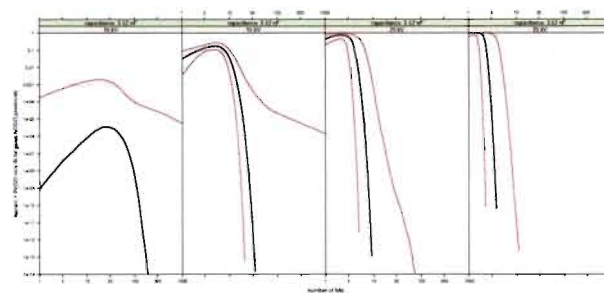
Data Analysis

- Scott and I are finishing up some general software that will utilize the product of CDFs
- The data analysis already performed only has one CDF where the location parameters is a function of log voltage and log energy
- We set $\lambda = 1$ (Weibull) as this is the most conservative for estimating lower tail quantiles

Posteriors: $\text{Pr}(\text{Go})$



Posteriors: Hazard Function



Where Do We Go From Here

- Model Assessment
- Develop frequentist based estimation to satisfy all philosophies

Informative Priors

Define

$V50$ = voltage for dielectric breakdown on half of units on 1st insult,

P = relative width of the soft threshold for voltage; namely

$$V10 = V50/(1 + P) \quad V90 = V50 \times (1 + P).$$

An expert who has tested other similar families of detonators provided plausible conservative ranges:

$$V50 : 10 \text{ kV to } 30 \text{ kV}$$

$$P : 10\% \text{ to } 50\%$$

We translate the “plausible” ranges into independent priors:

$$\log(V50) \sim N \text{ with } 0.1 \text{ below and above given range}$$

$$\log(1 + P) \sim N \text{ with } 0.1 \text{ below and above given range}$$

This implies priors on *functions of the parameters for the voltage CDF*:



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$$\alpha_1/\alpha_2 \sim \text{informative Normal}$$

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Details on Prior to Honor range for V50

$$\Pr\{\text{dielectric breakdown on 1st insult at voltage } V\} = \Phi\left(\frac{\log 1 - \alpha_1 - \alpha_2 \log(V50/V_0)}{e^\beta}\right)$$

where Φ is the SEV distribution CDF with median zero and density at zero.
Let $z_p = \Phi^{-1}(p)$ and note that $z_{0.5} = 0$.
Then, V50 satisfies

$$\frac{\log 1 - \alpha_1 - \alpha_2 \log(V50/V_0)}{e^\beta} = z_{0.5} = 0$$

and therefore

$$\log(V50) - \log(V_0) = -\alpha_1/\alpha_2.$$

Details on Prior to Honor range for V50

Take the nominal voltage (kV) to be the center of the elicited range on the log scale

$$\log(V_0) = (\log(10) + \log(30))/2$$

Therefore we obtain $\Pr(V50 < 10) = \Pr(V50 > 30) = 0.1$ by taking

$$\alpha_1/\alpha_2 \sim N \left[0, \left(\frac{\log(30/10)}{2 \times 1.28} \right)^2 \right].$$

Details on Prior to Honor range for P

V10 satisfies

$$\frac{\log 1 - \alpha_1 - \alpha_2 \log(V10/V_0)}{e^\beta} = z_{0.1}$$

and similarly for V90. Therefore

$$\log(V10/V_0) = \frac{\alpha_1 + z_{0.1}e^\beta}{-\alpha_2} \quad \text{and} \quad \log(V90/V_0) = \frac{\alpha_1 + z_{0.9}e^\beta}{-\alpha_2}.$$

But $V90/V10 = (1 + P)^2$ and therefore

$$\begin{aligned} \log(1 + P) &= \frac{1}{2} \log(V90/V10) = \frac{1}{2\alpha_2} \left[(\alpha_1 + z_{0.1}e^\beta) - (\alpha_1 + z_{0.9}e^\beta) \right] \\ &= \frac{e^\beta}{2} \frac{z_{0.1} - z_{0.9}}{\alpha_2} \end{aligned}$$

Therefore we obtain $\Pr(P < 0.1) = \Pr(P > 0.5) = 0.1$ by taking

$$\text{RHS above} \sim N \left[\frac{\log(1.1) + \log(1.5)}{2}, \left(\frac{\log(1.5) - \log(1.1)}{2 \times 1.28} \right)^2 \right].$$